

1.7 V to 5.5 V, 3 A Load Switch with Negative V_{IN} Tolerance

DESCRIPTION

The SiP32448 and SiP32449 are low resistance slew rate controlled load switches. The part operates from 1.7 V to 5.5 V supply and can tolerate negative voltage at input to -2 V. The integrated charge pump drivers enable the part with low on resistance over the wide input voltage range.

Both SiP32448 and SiP32449 feature a controlled soft-on slew rate of typical 2.5 ms that limits the inrush current for designs of heavy capacitive load and minimizes the resulting voltage droop at the power rails.

The SiP32448 and SiP32449 feature a constant low voltage control logic interface over the full operation voltage range. It can interface with low voltage control signals without extra level shifting circuit. When EN is left open, the part will not turn on until V_{IN} is greater than 2.5 V.

The SiP32449 has a output discharge to help discharge the output capacitor during shutdown mode for fast turn off.

The SiP32448 and SiP32449 have exceptionally low shutdown current and provides reverse blocking to prevent high current flowing into the power source when the switch is off or V_{IN} is ground.

Both SiP32448 and SiP32449 are available in TDFN4 package of 1.2 mm x 1.6 mm x 0.55 mm.

FEATURES

- 1.7 V to 5.5 V input voltage range
- Negative input voltage tolerance down to -2 V
- 38 m Ω typical R_{ON} from 1.8 V to 5 V
- 3 A maximum continuous switch current
- Slew rate controlled turn-on: 2.5 ms at 3.6 V
- Constant low control logic: V_{IH} = 1.15 V, V_{IL} = 0.7 V
- 2 V UVLO when EN is open
- Reverse current blocking when switch is off or V_{IN} is ground
- Output discharge (SiP32449)
- ESD protected
 - HBM: >6 kV
 - MM: >300 V
 - IEC61000-4-2 air discharge: >15 kV
 - IEC61000-4-2 contact discharge: >8 kV
- Compact TDFN4 package
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE
Available

APPLICATIONS

- PDAs / smart phones
- Notebook / netbook computers
- Tablet PC
- Portable media players
- Digital camera
- GPS navigation devices
- Data storage devices
- Optical, industrial, medical, and healthcare devices

TYPICAL APPLICATION CIRCUIT

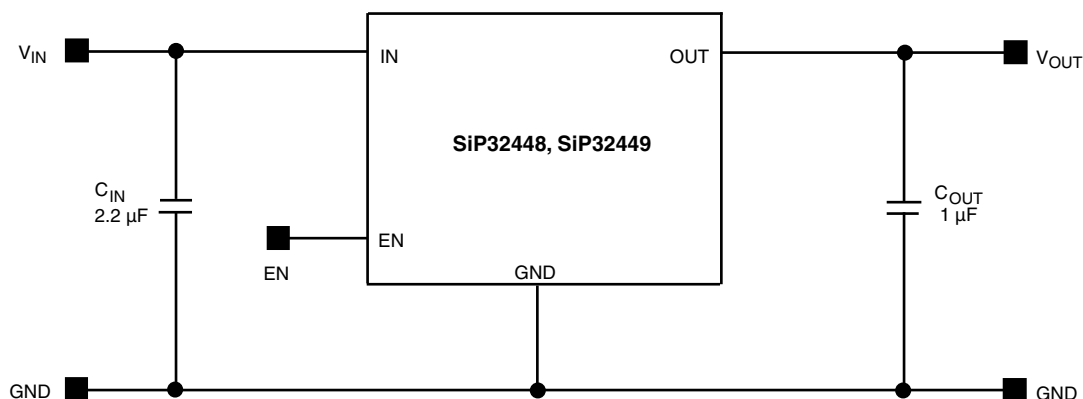


Fig. 1 - SiP32448, SiP32449 Typical Application Circuit

**ORDERING INFORMATION**

Part Number	Package	Marking	Output Discharge	Temperature Range
SiP32448DNP-T1-GE4	TDFN4 1.2 mm x 1.6 mm	Lx	No	-40 °C to +85 °C
SiP32449DNP-T1-GE4		Px	Yes	

Notes

- x = Lot code
- GE4 denotes halogen-free and RoHS compliant

ABSOLUTE MAXIMUM RATINGS

Parameter	Limit	Unit
Supply Input Voltage (V_{IN})	-2 to +6	V
Enable Input Voltage (V_{EN})	-2 to +6	
Output Voltage (V_{OUT})	-0.3 to +6	
Maximum Continuous Switch Current ($I_{max.}$) ^c	4	A
Maximum Repetitive Pulsed Current (1 ms, 10 % Duty Cycle) ^c	7	
Maximum Non-Repetitive Pulsed Current (100 μ s, EN = Active) ^c	12	
Junction Temperature (T_J)	-40 to +150	°C
Thermal Resistance (θ_{JA}) ^a	170	°C/W
Power Dissipation (P_D) ^{a,b}	735	mW
ESD Rating	HBM	6 kV
	MM	300 V
	IEC41000-4-2 Air Discharge ^d	15 kV
	IEC41000-4-2 Contact Discharge ^d	8 kV

Notes

- Device mounted with all leads and power pad soldered or welded to PC board, see PCB layout.
- Derate 5.9 mW/°C above $T_A = 25$ °C, see PCB layout.
- $T_A = 25$ °C, see PCB layout.
- Tested on V_{IN} with 2.2 μ F C_{IN} . V_{IN} connected to micro-USB connector.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating/conditions for extended periods may affect device reliability.

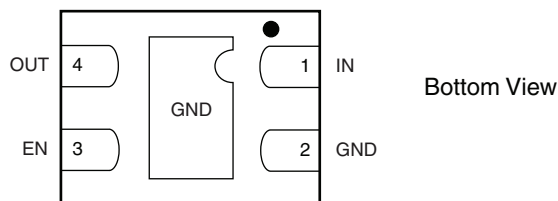
RECOMMENDED OPERATING RANGE

Parameter	Limit	Unit
Input Voltage Range (V_{IN})	1.7 to 5.5	V
Operating Junction Temperature Range (T_J)	-40 to +125	°C

SPECIFICATIONS						
Parameter	Symbol	Test Conditions Unless Specified $V_{IN} = 5\text{ V}$, $T_A = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ (Typical values are at $T_A = 25\text{ }^{\circ}\text{C}$)	Limits -40 $^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$			Unit
			Min. ^a	Typ. ^b	Max. ^a	
Operating Voltage ^c	V_{IN}		1.7	-	5.5	V
Negative Input Voltage Tolerance	I_{NEG}	$V_{IN} = -2\text{ V}$	-	-15	-	mA
Under Voltage Lock Out	UVLO _{H-L}	EN = open, 25 $^{\circ}\text{C}$ (switch On to Off)	-	-	2	V
	UVLO _{L-H}	EN = open, 25 $^{\circ}\text{C}$ (switch Off to On)	2.5	-	-	
UVLO Hysteresis	UVLO _{HYS}	EN = open, 25 $^{\circ}\text{C}$	-	0.25	-	
Quiescent Current	I_Q	$V_{IN} = 1.8\text{ V}$, EN = active	-	35	50	μA
		$V_{IN} = 2.5\text{ V}$, EN = active	-	54	90	
		$V_{IN} = 3.6\text{ V}$, EN = active	-	78	110	
		$V_{IN} = 4.3\text{ V}$, EN = active	-	93	130	
		$V_{IN} = 5\text{ V}$, EN = active	-	110	180	
Off Supply Current	$I_{Q(off)}$	EN = inactive, OUT = open	-	8	18	
Off Switch Current	$I_{DS(off)}$	EN = inactive, OUT = GND	-	-	1	
Reverse Blocking Current	I_{RB}	$V_{OUT} = 5\text{ V}$, $V_{IN} = 0\text{ V}$, $V_{EN} = \text{inactive}$	-	-	10	
On-Resistance	$R_{DS(on)}$	$V_{IN} = 1.8\text{ V}$, $I_L = 500\text{ mA}$, $T_A = 25\text{ }^{\circ}\text{C}$	-	38	43	$\text{m}\Omega$
		$V_{IN} = 2.5\text{ V}$, $I_L = 500\text{ mA}$, $T_A = 25\text{ }^{\circ}\text{C}$	-	38	43	
		$V_{IN} = 3.6\text{ V}$, $I_L = 500\text{ mA}$, $T_A = 25\text{ }^{\circ}\text{C}$	-	38	43	
		$V_{IN} = 4.3\text{ V}$, $I_L = 500\text{ mA}$, $T_A = 25\text{ }^{\circ}\text{C}$	-	38	43	
		$V_{IN} = 5\text{ V}$, $I_L = 500\text{ mA}$, $T_A = 25\text{ }^{\circ}\text{C}$	-	38	43	
On-Resistance Temp.-Coefficient	TC_{RDS}		-	3100	-	ppm/ $^{\circ}\text{C}$
EN Input Low Voltage ^c	V_{IL}	$V_{IN} = 1.8\text{ V}$ to 5.5 V	-	-	0.7 ^d	V
EN Input High Voltage ^c	V_{IH}		1.15 ^d	-	-	
EN Input Leakage	I_{SINK}	$V_{EN} = 5.5\text{ V}$	-6	-	6	μA
Output Pulldown Resistance	R_{PD}	EN = inactive, $T_A = 25\text{ }^{\circ}\text{C}$ (for SiP32449 only)	-	210	280	Ω
Output Turn-On Delay Time	$t_{d(on)}$	$V_{IN} = 3.6\text{ V}$, $R_{load} = 10\text{ }\Omega$, $T_A = 25\text{ }^{\circ}\text{C}$	-	1.35	-	ms
Output Turn-On Rise Time	$t_{(on)}$		1	1.7	3.8	
Output Turn-Off Delay Time	$t_{d(off)}$		-	-	0.005	

Notes

- a. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum.
b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
c. For V_{IN} outside this range consult typical EN threshold curve.
d. Not tested, guarantee by design.

PIN CONFIGURATION

Fig. 2 - TDFN4 1.2 mm x 1.6 mm Package

PIN DESCRIPTION		
Pin Number	Name	Function
1	IN	This is the input pin of the switch
2	GND	Ground connection
3	EN	Enable input
4	OUT	This is the output pin of the switch

BLOCK DIAGRAM

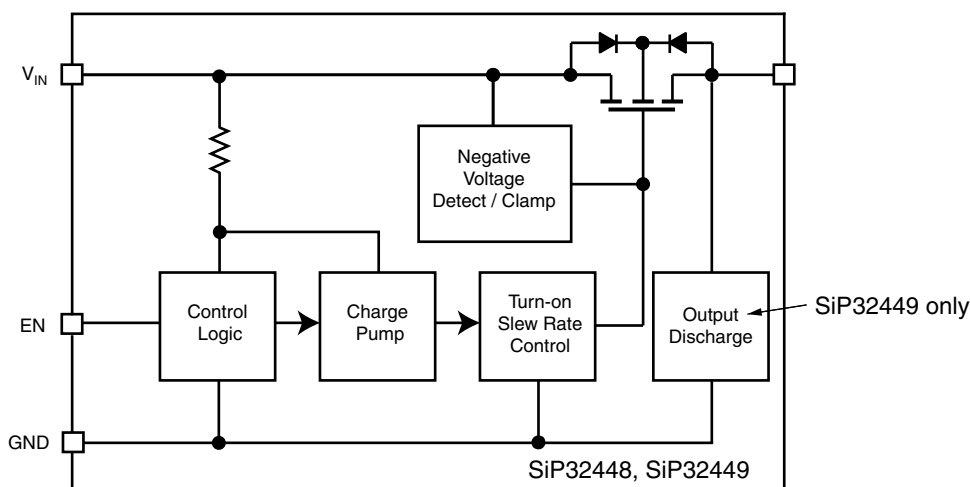


Fig. 3 - Functional Block Diagram

DETAILED DESCRIPTION

SiP32448 and SiP32449 are advanced slew rate controlled high side load switches with an integrated N-channel power switch. When the device is enabled the gate of the power switch is turned on at a controlled rate to avoid excessive inrush current. Once fully on the gate to source voltage of the power switch is biased at a constant level. The design gives a flat on resistance throughout the operating voltages. A special reverse blocking circuitry prevents current flowing from output to input when the switch is off. The V_{IN} and EN pin can tolerate -2 V voltage without drawing excessive current.

APPLICATION INFORMATION

Input Capacitor

In general, under steady state conditions the SiP32448 and SiP32449 do not require an input capacitor. Nevertheless, an input bypass capacitor is recommended in order to reduce the input voltage drop caused by transient inrush currents. Commonly, a 2.2 μF ceramic capacitor is sufficient and should be placed in close proximity to V_{IN} and GND pins. A higher value input capacitor can help to further reduce the voltage drop. Ceramic capacitors are recommended for their low ESR characteristic.

Output Capacitor

While these devices work without an output capacitor, a 1 μF or higher value capacitor across V_{OUT} and GND is recommended in order to handle potential load transient conditions. In the event that the switch is turning off while running high current, circuit stray inductances might force the output to some negative voltage in order to mitigate this phenomenon a proper output capacitor is required.

Enable

The device is logic high active. Enable pin voltage can exceed V_{IN} as long as it is within the absolute maximum rating range. The EN pin is compatible with both TTL and CMOS logic voltage levels. The part features a constant

control logic threshold over the operation voltage range. When enable pin is left open, a built-in voltage divider sets the internal logic. The switch will turn on when the V_{IN} exceeds the UVLO trip point.

Reverse Voltage Protection

The SiP32448 and SiP32449 contain a reverse blocking circuitry to protect the current from going to the input from the output when the switch is off. Reverse blocking works for input voltage as low as 0 V.

In case the EN pin is left open, the reverse blocking circuitry will prevent current flow from output pin to input pin if the output voltage is higher by at least 1 V than the input voltage.

THERMAL CONSIDERATIONS

The maximum allowed DC Current depends on the thermal condition in which the device operates. In order to calculate max allowed DC current, first the max power dissipation should be considered.

The SiP32448 and SiP32449 are packaged in a TDFN4 1.2 mm x 1.6 mm package which has a thermal resistance of $\theta_{JA}^a = 170^\circ\text{C/W}$.

Note

- Device mounted with all leads and power pad soldered or welded to PC board, see PCB layout. For any other layout configuration the actual junction to ambient thermal impedance should be considered

The following formula shows the maximum allowed power dissipation as a function of the ambient temperature T_A when the maximum junction temperature is limited to $T_{J(max)} = 125^\circ\text{C}$:

$$P_{max} = \frac{T_{J(max)} - T_A}{\theta_{JA}} = \frac{125 - T_A}{170}$$

For example at ambient temperature of 70°C , the maximum power dissipation will be limited to about 324 mW.

In order to calculate the maximum allowed DC current the switch $R_{DS(on)}$ temperature dependency should be considered.

As an example let us calculate maximum load current at $T_A = 70^\circ\text{C}$ and input voltage of 1.8 V. At this input voltage the $R_{DS(on)}$ at 25°C 43 m Ω (see specification table). The $R_{DS(on)}$ at 125°C can be extrapolated from this data using the following formula:

$$R_{DS(on)_{125^\circ\text{C}}} = R_{DS(on)_{25^\circ\text{C}}} \times (1 + T_C \times (T_{J_{max}} - 25)/100)$$

Where T_C is the $R_{DS(on)}$ temperature coefficient expressed in percent change per degree C.

For SiP32448 the approximated value is 0.31 %/ $^\circ\text{C}$. $T_{J_{max}}$ is the maximum allowed junction temperature (125°C).

Therefore,

$$R_{DS(on) \text{ (at } 125^\circ\text{C)}} = 43 \text{ m}\Omega \times (1 + 0.31 \times (125 - 25)/100) \approx 57 \text{ m}\Omega$$

The maximum current limit is then determined by

$$I_{LOAD \text{ (max.)}} < \sqrt{\frac{P \text{ (max.)}}{R_{DS(on)}}}$$

Which in this case is 2.38 A.

Due to device limitation the max switch DC current should exceed 3 A in any condition.

To obtain the highest power dissipation the power pad of the device should be connected to a heat sink on the printed circuit board. Figure 4 shows a typical PCB layout. All copper traces and vias for the V_{IN} and V_{OUT} pins should be sized adequately to carry the maximum continuous current.

Negative Input Voltage

The SiP32448 and SiP32449 can withstand maximum negative 2 V at its input due to any spike from abnormal or fault condition of the system.

Recommended Board Layout

For improved performance, all traces should be as short as possible to minimize stray inductances and parasitic effects. The input and output capacitors should be kept as close as possible to the input and output pins respectively. Connecting the central exposed pad to GND, using wide traces for input, output, and GND help reducing the case to ambient thermal impedance. See fig. 4.

BOARD LAYOUT

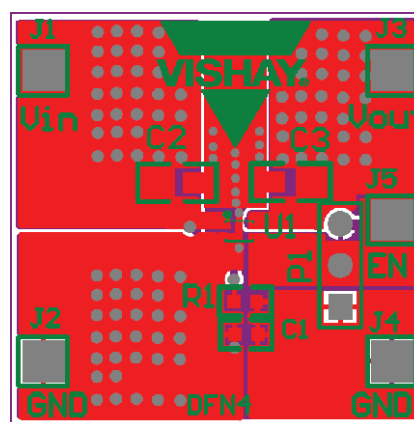


Fig. 4 - Recommended Board Layout

TYPICAL APPLICATION SCHEMATIC

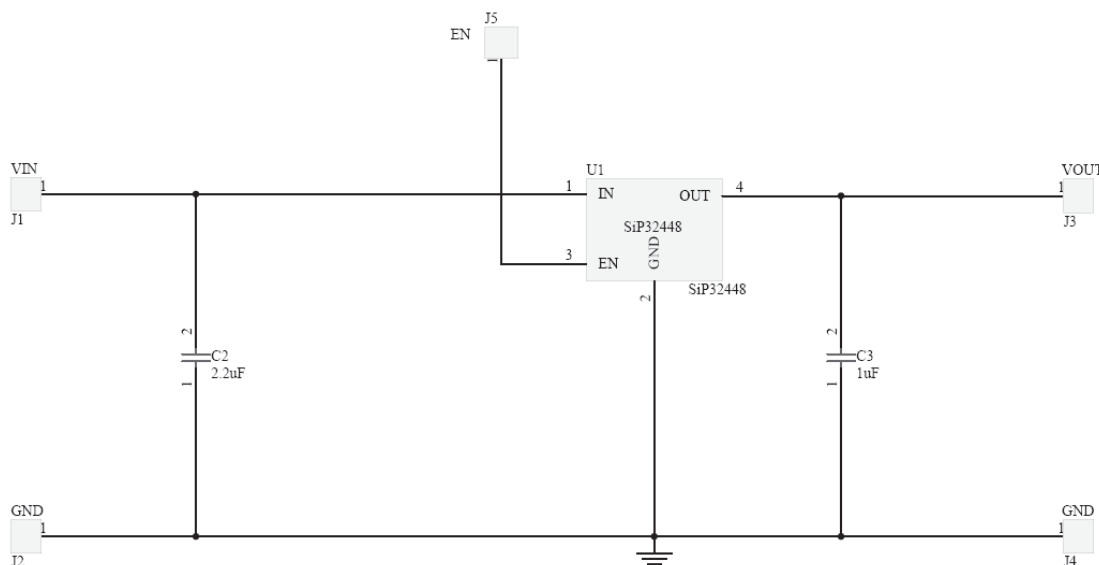
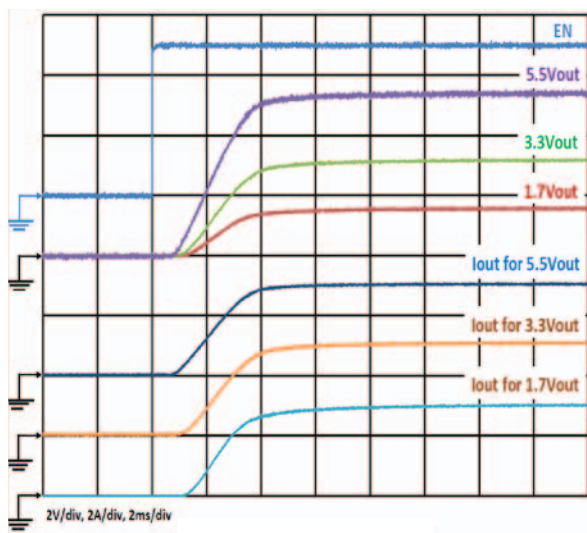


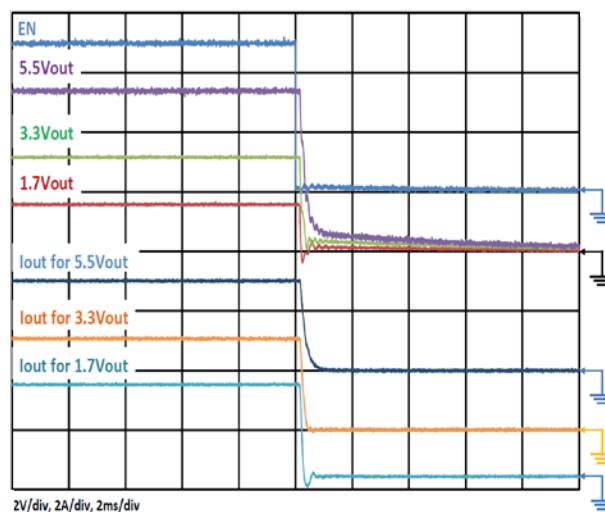
Fig. 5 - Application Schematic



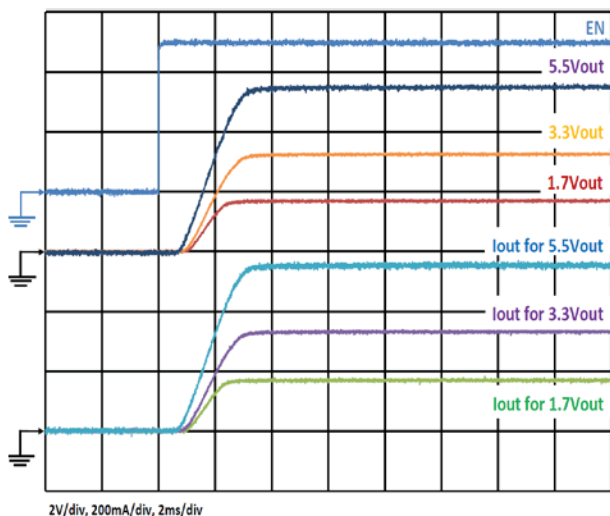
TYPICAL ENABLE POWER ON AND OFF WAVEFORMS



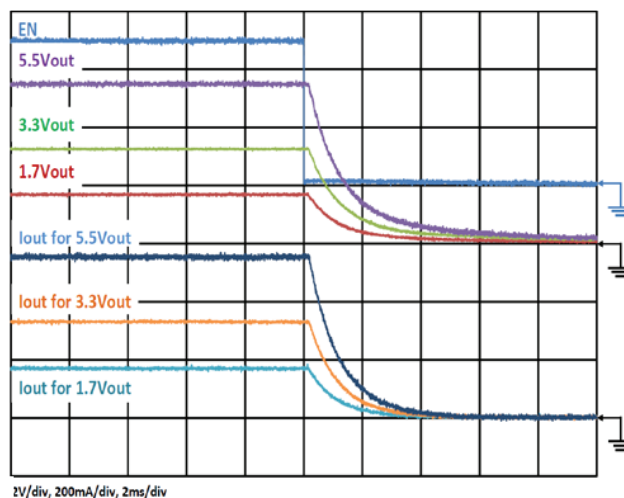
Typical Turn-On Delay, Rise Time,
 $C_{OUT} = 1 \mu F$, $C_{IN} = 2.2 \mu F$, $I_{OUT} = 3 A$



Typical Turn-Off Delay, Fall Time,
 $C_{OUT} = 1 \mu F$, $C_{IN} = 2.2 \mu F$, $I_{OUT} = 3 A$



Typical Turn-On Delay, Rise Time,
 $C_{OUT} = 1 \mu F$, $C_{IN} = 2.2 \mu F$, $R_{OUT} = 10 \Omega$



Typical Turn-Off Delay, Fall Time,
 $C_{OUT} = 1 \mu F$, $C_{IN} = 2.2 \mu F$, $R_{OUT} = 10 \Omega$



TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

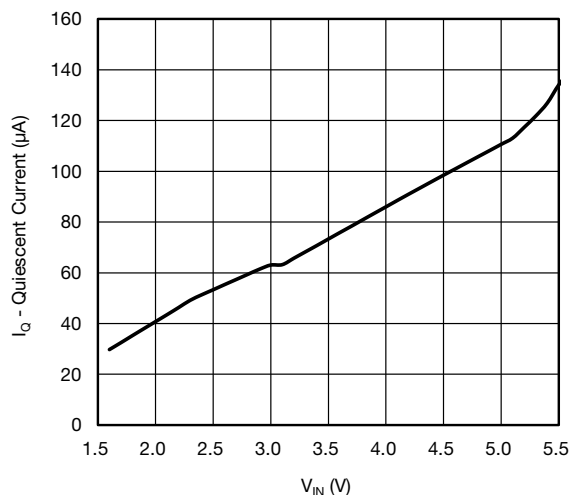


Fig. 6 - Quiescent Current vs. Input Voltage

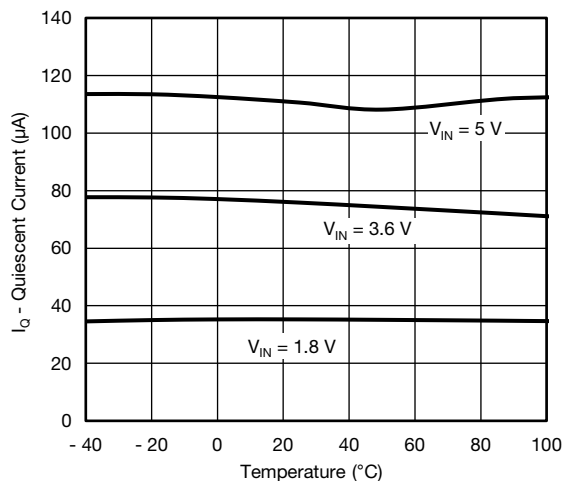


Fig. 9 - Quiescent Current vs. Temperature

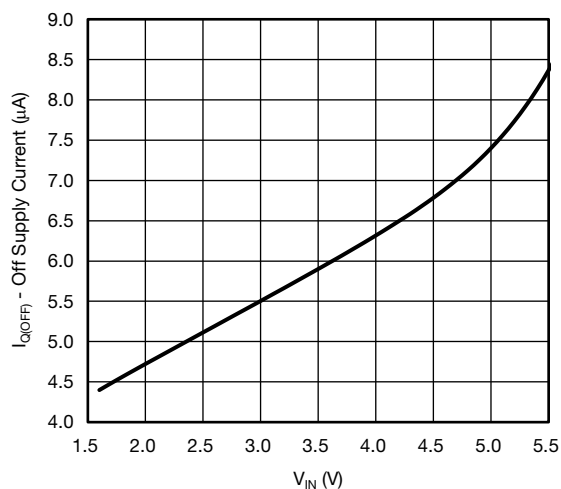


Fig. 7 - Off Supply Current vs. Input Voltage

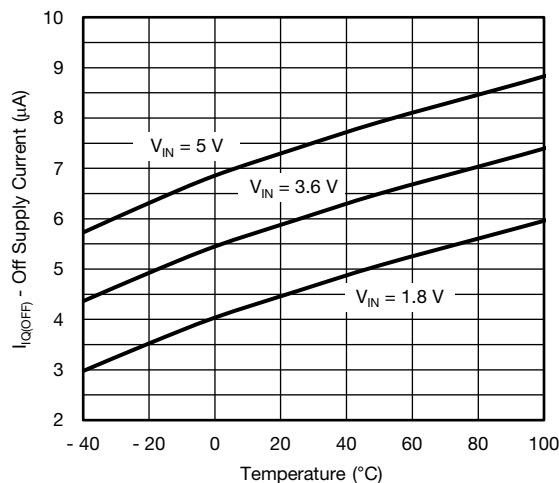


Fig. 10 - Off Supply Current vs. Temperature

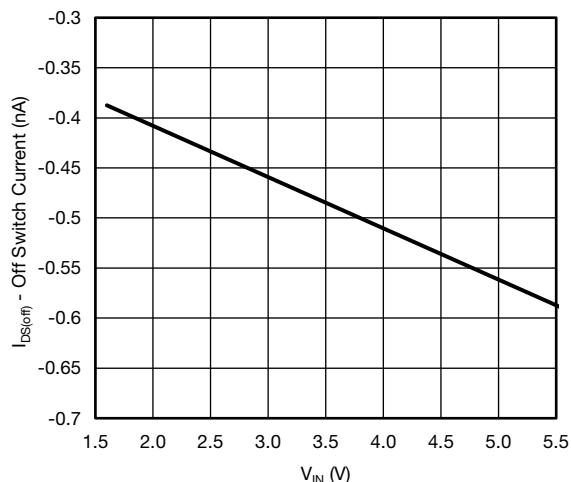


Fig. 8 - Off Switch Current vs. Input Voltage

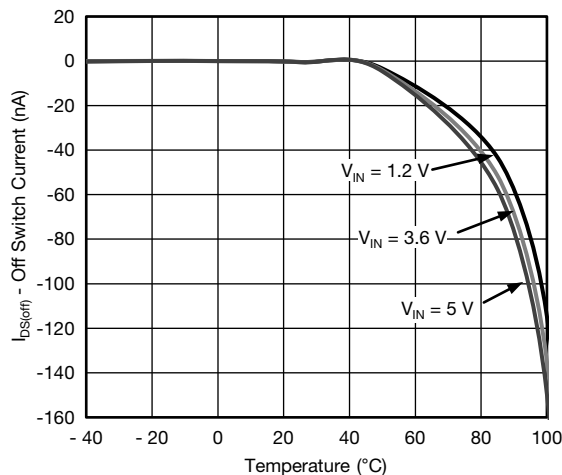


Fig. 11 - Off Switch Current vs. Temperature



TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

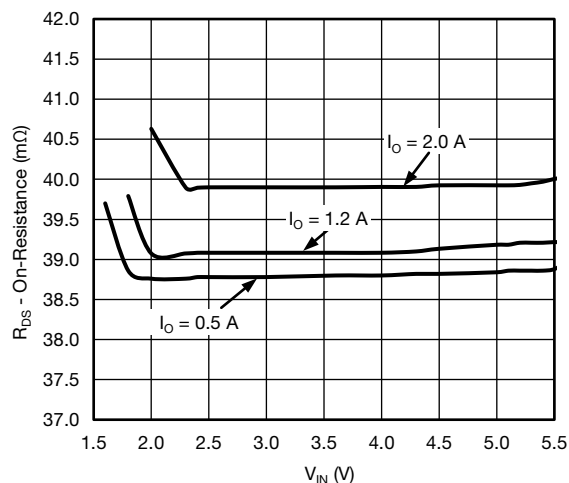


Fig. 12 - On-Resistance vs. Input Voltage

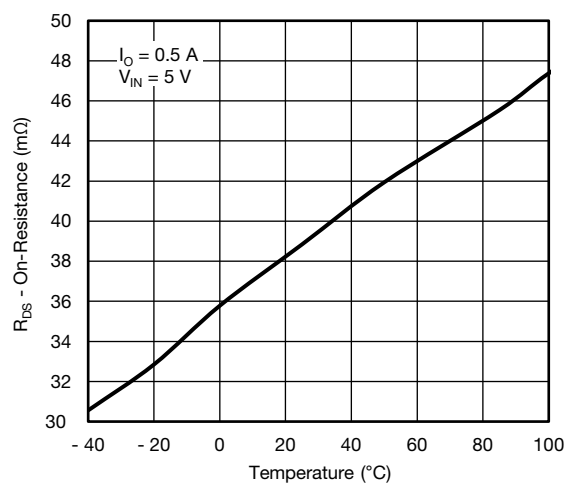


Fig. 15 - On-Resistance vs. Temperature

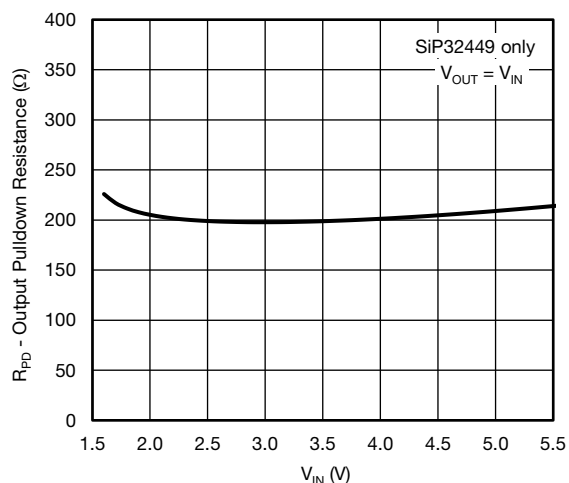


Fig. 13 - Output Pulldown Resistance vs. V_{IN}

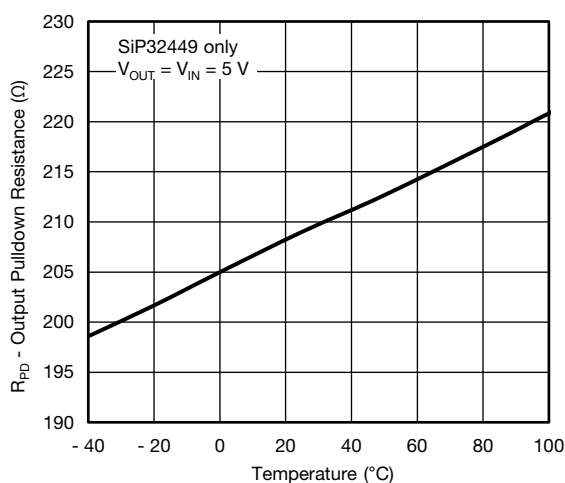


Fig. 16 - Output Pulldown Resistance vs. Temperature

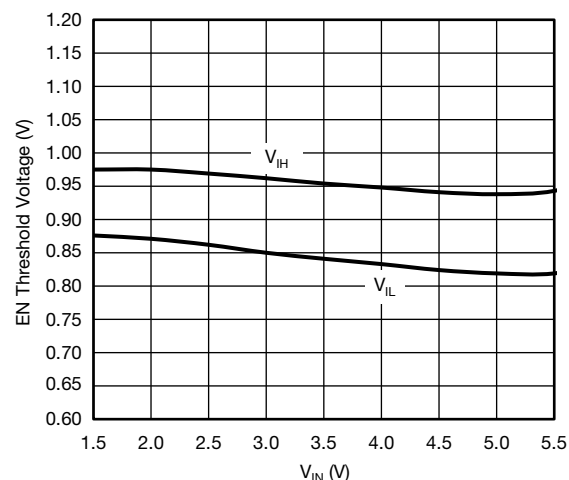


Fig. 14 - Threshold Voltage vs. Input Voltage

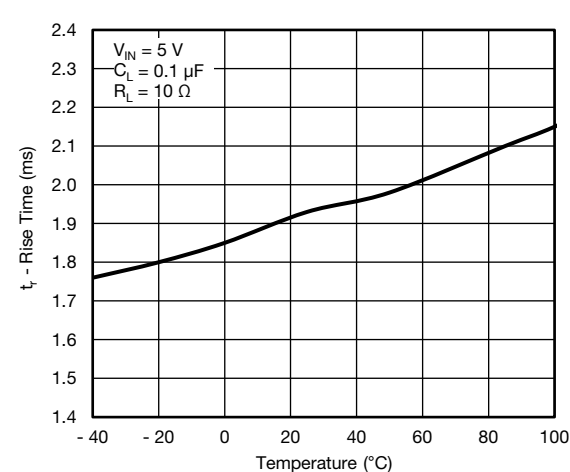
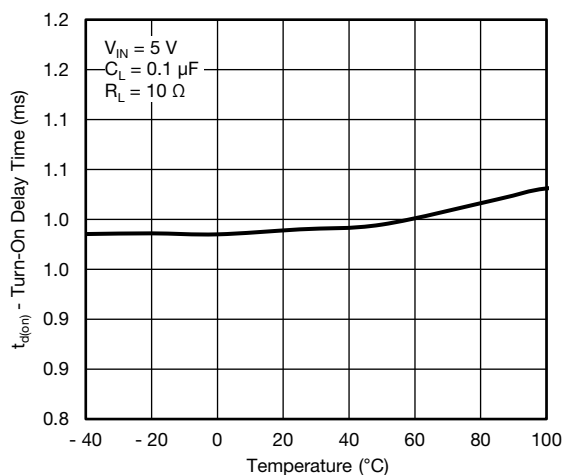
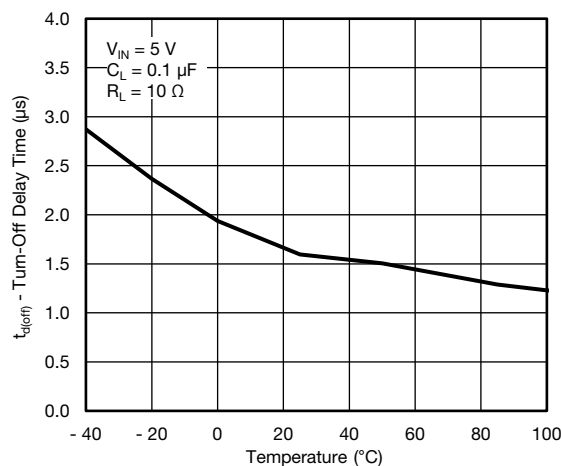
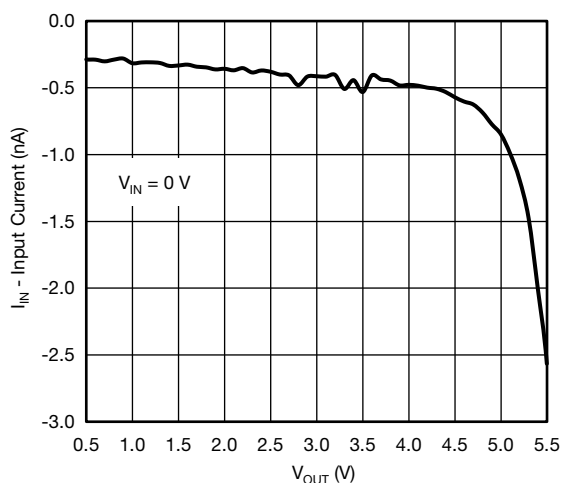
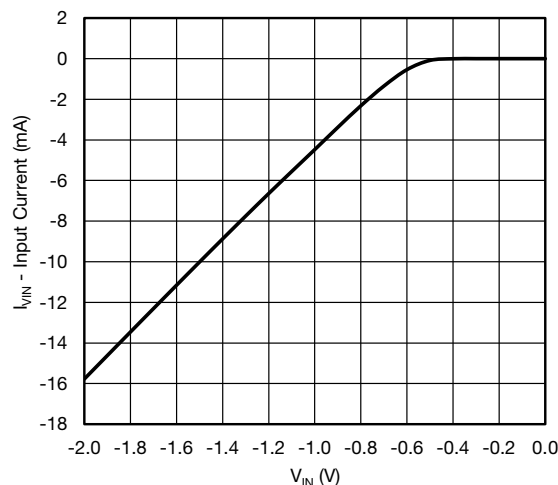


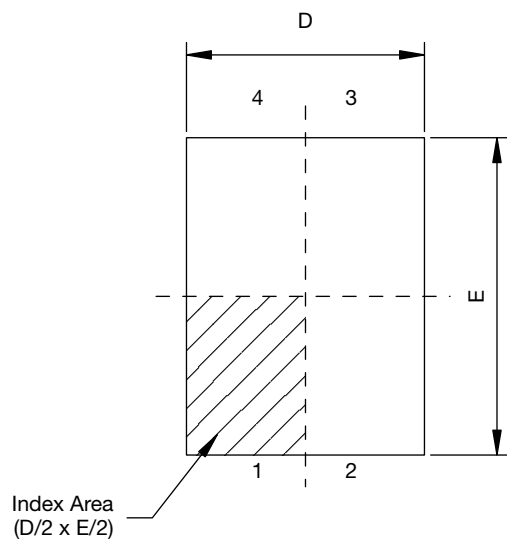
Fig. 17 - Rise Time vs. Temperature

TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

Fig. 18 - Turn-On Delay Time vs. Temperature

Fig. 20 - Turn-Off Delay Time vs. Temperature

Fig. 19 - Reverse Blocking Current

Fig. 21 - Negative Input Voltage Tolerance

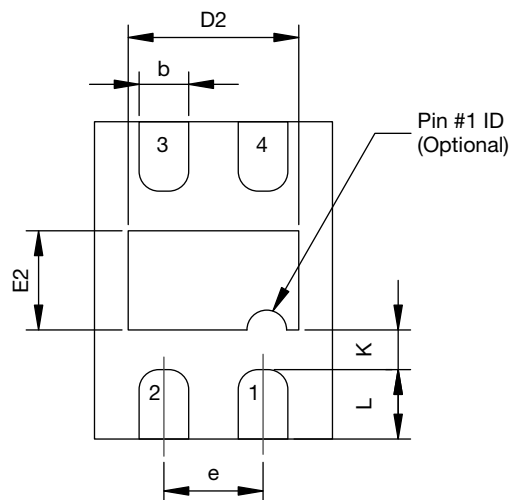
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62959.



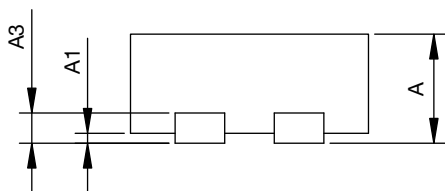
TDFN4 1.2 x 1.6 Case Outline



Top View



Bottom View



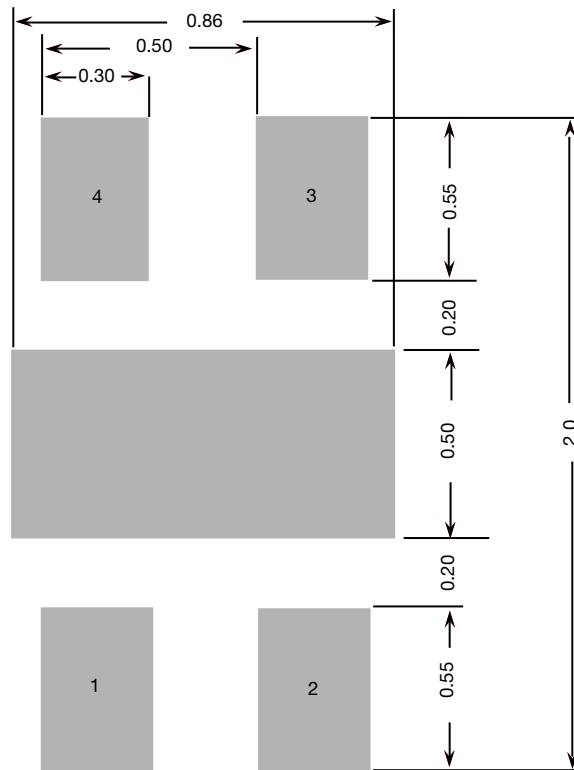
Side View

DIM.	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.45	0.55	0.60	0.017	0.022	0.024
A1	0.00	-	0.05	0.00	-	0.002
A3	0.15 REF. or 0.127 REF. ⁽¹⁾			0.006 or 0.005 ⁽¹⁾		
b	0.20	0.25	0.30	0.008	0.010	0.012
D	1.15	1.20	1.25	0.045	0.047	0.049
D2	0.81	0.86	0.91	0.032	0.034	0.036
e	0.50 BSC			0.020		
E	1.55	1.60	1.65	0.061	0.063	0.065
E2	0.45	0.50	0.55	0.018	0.020	0.022
K	0.25 typ.			0.010 typ.		
L	0.25	0.30	0.35	0.010	0.012	0.014
ECN: T16-0143-Rev. C, 18-Apr-16 DWG: 5995						

Note

⁽¹⁾ The dimension depends on the leadframe that assembly house used.

RECOMMENDED MINIMUM PADS FOR TDFN4 1.2 x 1.6



Recommended Minimum Pads
Dimensions in mm



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9